



(51) International Patent Classification:
H01L 29/786 (2006.01) *G02F 1/136* (2006.01)

(21) International Application Number:
PCT/US2009/047966

(22) International Filing Date:
19 June 2009 (19.06.2009)

(25) Filing Language: English

(26) Publication Language: English

(30) Priority Data:
61/077,831 2 July 2008 (02.07.2008) US
61/117,744 25 November 2008 (25.11.2008) US
61/117,747 25 November 2008 (25.11.2008) US
12/411,195 25 March 2009 (25.03.2009) US

(71) Applicant (for all designated States except US): **APPLIED MATERIALS, INC.** [US/US]; 3050 Bowers Avenue, Santa Clara, CA 95054 (US).

(72) Inventor; and

(75) Inventor/Applicant (for US only): **YE, Yan** [US/US]; 13271 Via Arriba Drive, Saratoga, CA 95070 (US).

(74) Agents: **PATTERSON, B. Todd** et al.; Patterson & Sheridan, L.L.P., 3040 Post Oak Blvd., Suite 1500, Houston, TX 77056-6582 (US).

(81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM,

AO, AT, AU, AZ, BA, BB, BG, BH, BR, BW, BY, BZ, CA, CH, CL, CN, CO, CR, CU, CZ, DE, DK, DM, DO, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LY, MA, MD, ME, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PE, PG, PH, PL, PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, ST, SV, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW.

(84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HR, HU, IE, IS, IT, LT, LU, LV, MC, MK, MT, NL, NO, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

Published:

- with international search report (Art. 21(3))
- before the expiration of the time limit for amending the claims and to be republished in the event of receipt of amendments (Rule 48.2(h))

(88) Date of publication of the international search report:
3 March 2011

(54) Title: THIN FILM TRANSISTORS USING MULTIPLE ACTIVE CHANNEL LAYERS

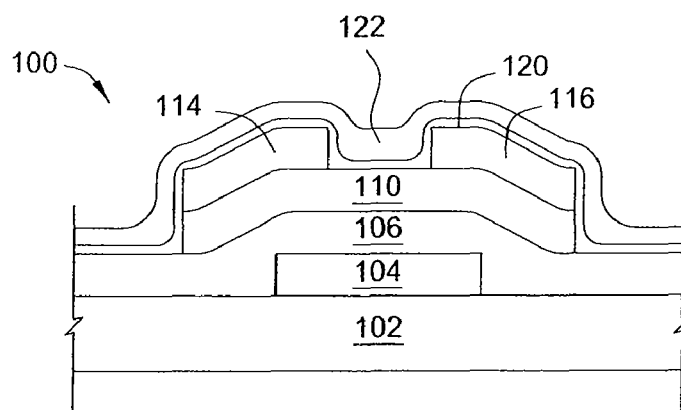


FIG. 1G

(57) Abstract: Embodiments disclosed herein generally relate to TFTs and methods of fabricating the TFTs. In TFTs, the active channel carries the current between the source and drain electrodes. By tailoring the composition of the active channel, the current can be controlled. The active channel may be divided into three layers, a gate control layer, a bulk layer, and an interface control layer. The separate layers may have different compositions. Each of the gate control, bulk and interface control layers may additionally comprise multiple layers that may have different compositions. The composition of the various layers of the active channel comprise oxygen, nitrogen, and one or more elements selected from the group consisting of zinc, indium, cadmium, tin, gallium and combinations thereof. By varying the composition among the layers, the mobility, carrier concentration and conductivity of the various layers may be controlled to produce a TFT having desired properties.



INTERNATIONAL SEARCH REPORT

International application No.
PCT/US2009/047966**A. CLASSIFICATION OF SUBJECT MATTER****H01L 29/786(2006.01)i, G02F 1/136(2006.01)i**

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

H01L 29/786; H01L 29/784; H01L 21/84; G02F 1/136; H01L 21/336

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Korean utility models and applications for utility models

Japanese utility models and applications for utility models

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

eKOMPASS(KIPO internal) & Keywords: "multiple" and "active" and "channel"

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	KR 10-2001-0011855 A (HYNIX SEMICONDUCTOR INC.) 15 February 2001 See the abstract; figs. 1-2; claims 1-3.	1-15
A	JP 06-045354 A (SEMICONDUCTOR ENERGY LAB CO LTD) 18 February 1994 See the abstract; figs. 1-5; paragraphs [0008]-[0072].	1-15
A	US 2006-0286725 A1 (HUA-CHI CHENG et al.) 21 December 2006 See the abstract; figs. 1-6; paragraphs [0026]-[0036].	1-15



Further documents are listed in the continuation of Box C.



See patent family annex.

* Special categories of cited documents:

"A" document defining the general state of the art which is not considered to be of particular relevance

"E" earlier application or patent but published on or after the international filing date

"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of citation or other special reason (as specified)

"O" document referring to an oral disclosure, use, exhibition or other means

"P" document published prior to the international filing date but later than the priority date claimed

"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art

"&" document member of the same patent family

Date of the actual completion of the international search

24 DECEMBER 2010 (24.12.2010)

Date of mailing of the international search report

27 DECEMBER 2010 (27.12.2010)

Name and mailing address of the ISA/KR

Korean Intellectual Property Office
Government Complex-Daejeon, 139 Seonsa-ro, Seo-
gu, Daejeon 302-701, Republic of Korea

Facsimile No. 82-42-472-7140

Authorized officer

Lee, Sang Ho

Telephone No. 82-42-481-8221



INTERNATIONAL SEARCH REPORT

Information on patent family members

International application No.

PCT/US2009/047966

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
KR 10-2001-0011855 A	15.02.2001	None	
JP 06-045354 A	18.02.1994	JP 03-255942 B2	30.11.2001
		JP 3255942 B2	12.02.2002
		US 2002-0042171 A1	11.04.2002
		US 2002-0127785 A1	12.09.2002
		US 2002-0130322 A1	19.09.2002
		US 2005-0017243 A1	27.01.2005
		US 2008-0044962 A1	21.02.2008
		US 5648662 A1	15.07.1997
		US 5811328 A1	22.09.1998
		US 6124155 A1	26.09.2000
		US 6166399 A1	26.12.2000
		US 6335213 B1	01.01.2002
		US 6756258 B2	29.06.2004
		US 6797548 B2	28.09.2004
		US 6847064 B2	25.01.2005
		US 7507991 B2	24.03.2009
US 2006-0286725 A1	21.12.2006	CN 100508139 C	01.07.2009
		CN 1881549 A	20.12.2006
		CN 1881549 C0	20.12.2006
		TW 200701469 A	01.01.2007
		US 7381586 B2	03.06.2008